

/ Descriptions

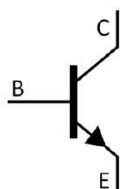
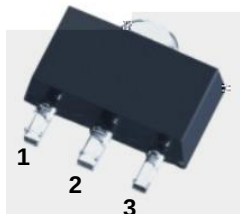
SOT-89

NPN

Silicon NPN transistor in a SOT-89 Plastic Package.

/ Features h_{FE} , V_{CEO} , 2SA812THigh h_{FE} and V_{CEO} , complementary pair with 2SA812T.**/ Applications**

Audio frequency general amplifier application.

/ Equivalent Circuit**/ Pinning**

PIN1 Base

PIN 2 Collector

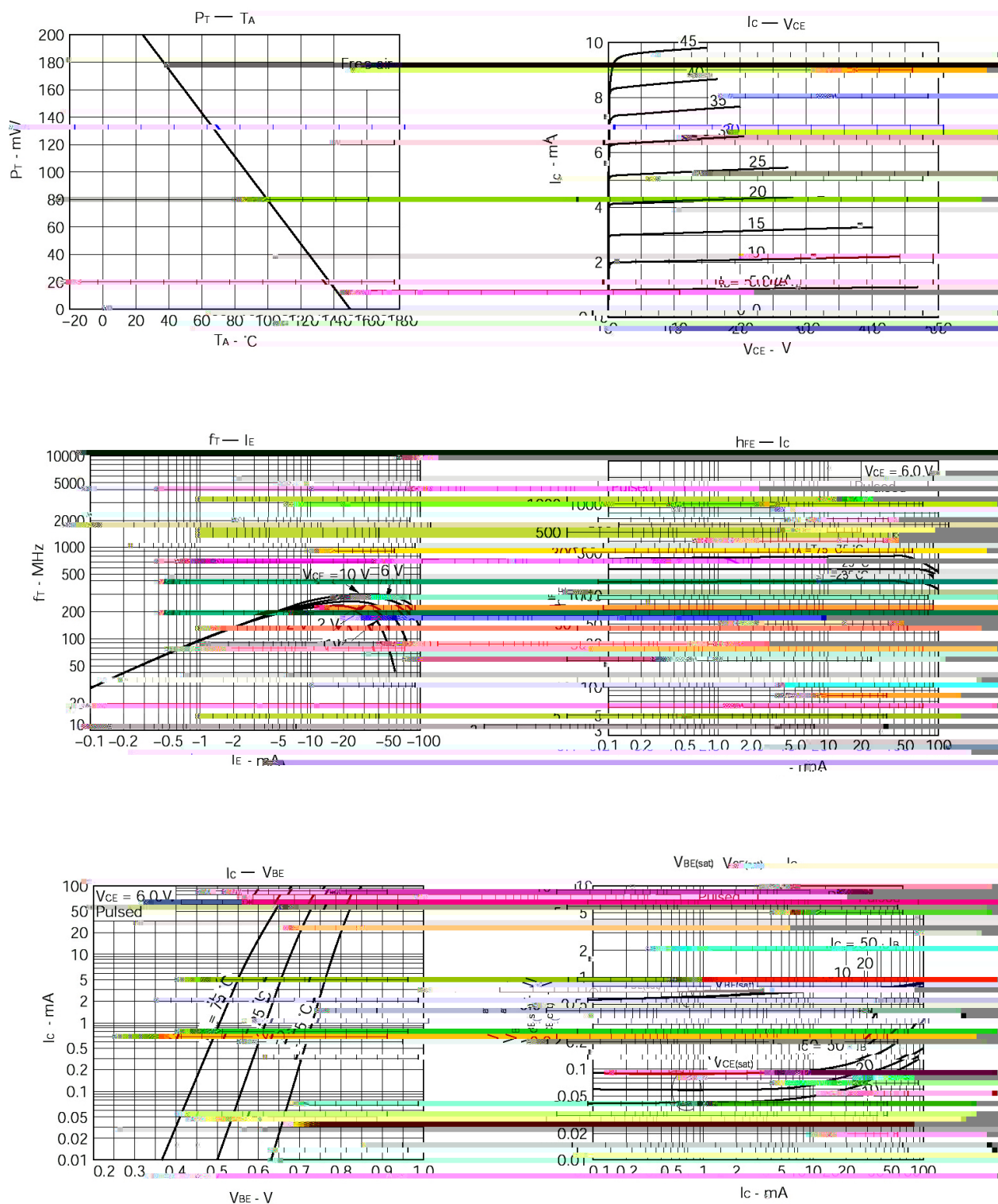
PIN 3 Emitter

/ Marking

h_{FE} Classifications Symbol	O	Y	G	L
h_{FE} Range	90` 180	135` 270	200` 400	300` 600
Marking	HL4	HL5	HL6	HL7

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current-Continuous	I_C	100	mA
w()Tj10.5 0	0	10.5	330.12

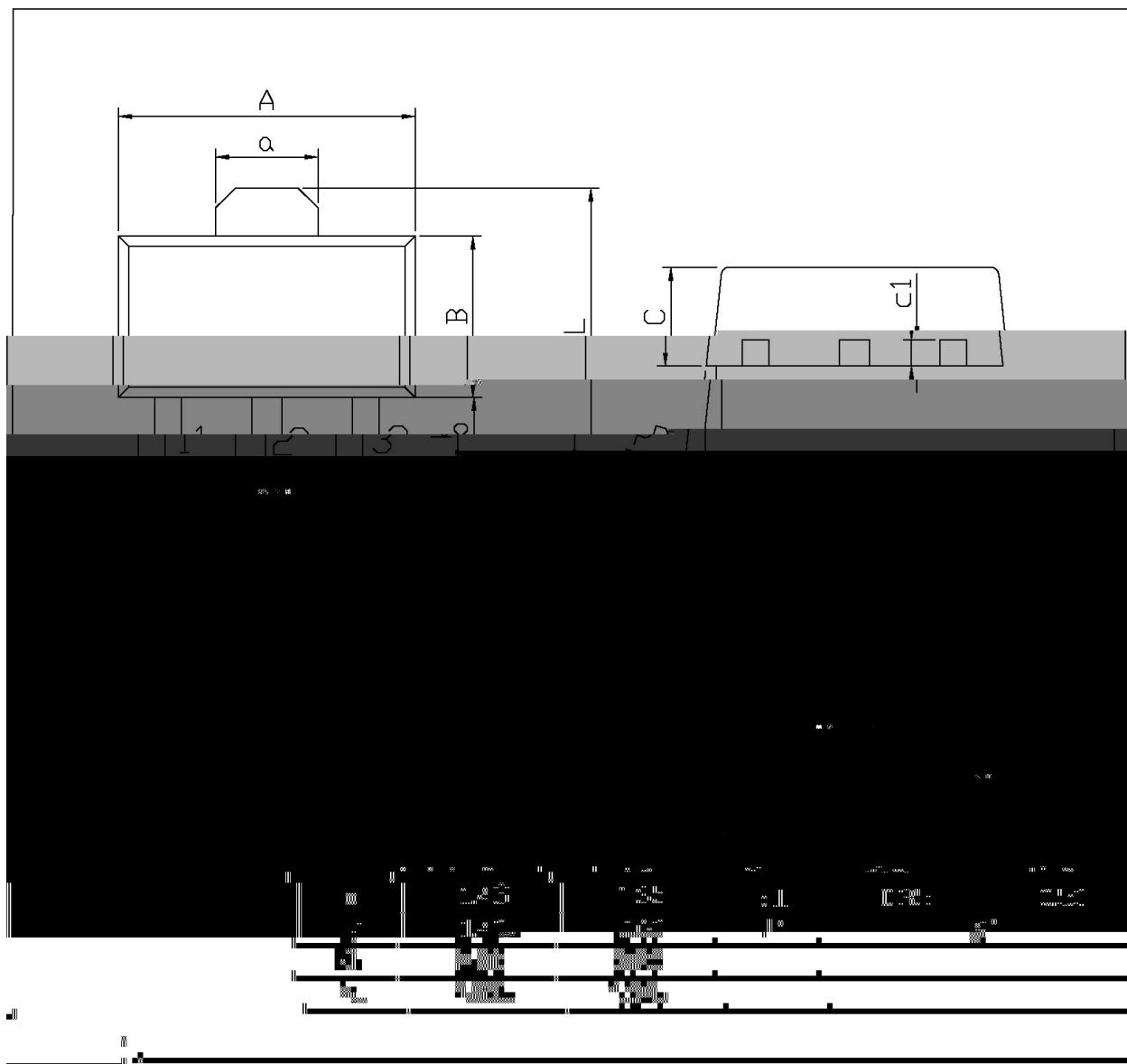
/ Electrical Characteristic Curve



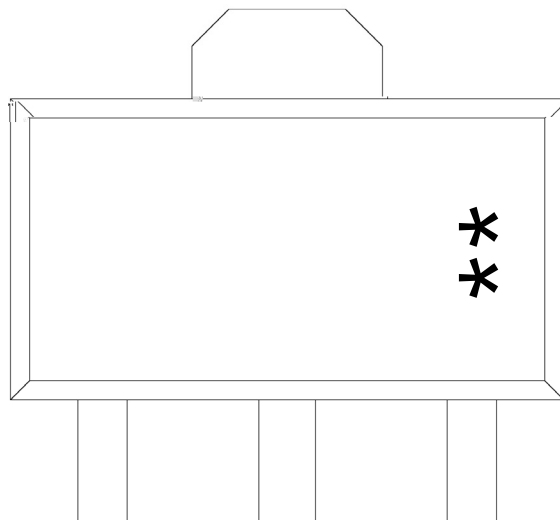
/ Package Dimensions

SOT-89

单位: mm



/ Marking Instructions



H

L5

**

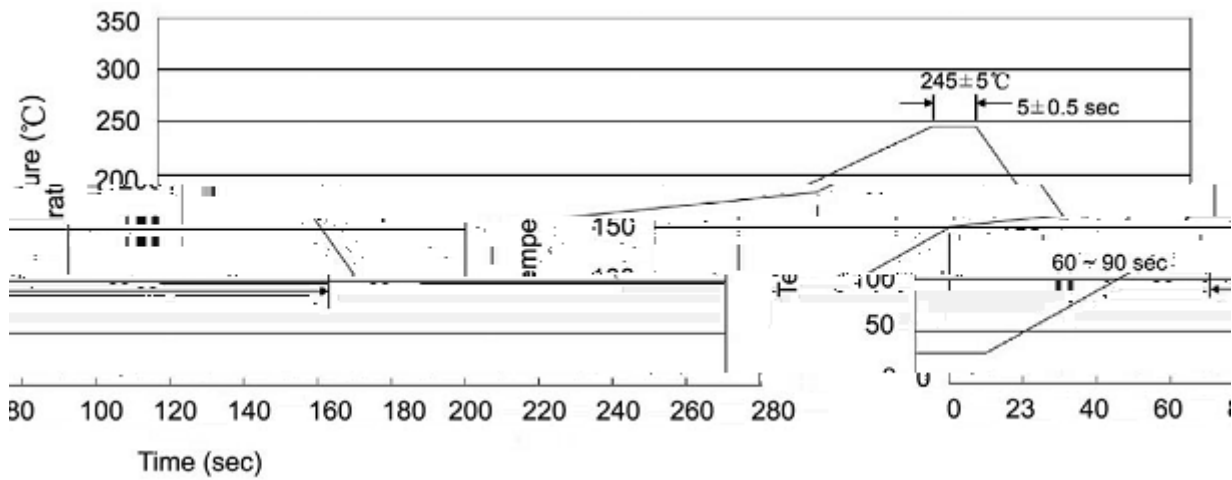
Note:

H: Company Code.

L5: Product Type.

** : Lot No. Code, code change with Lot No.

() /



Note:

- 1

25 150

60 90sec;

1.Preheating:25~150 , Time:60~90sec.
- 2

245±5

5±0.5sec;

2.Peak Temp.:245±5 , Duration:5±0.5sec.
- 3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-89	1,000	7	7,000	8	56,000	7 p ×12	180×120×180	385×257×392

/ Notices